# 2SD1628



http://onsemi.com

## Bipolar Transistor 20V, 5A, Low VCE(sat), NPN Single PCP

#### **Applications**

· Strobe DC-DC converters, relay drivers, hammer drivers, lamp drivers, motor drovers

#### **Features**

· Low saturation voltage

· High hFE

- · Large current capacity
- · Very small size making it easy to provide highdensity, small-sized hybrid IC's
- · Halogen free compliance

#### **Specifications**

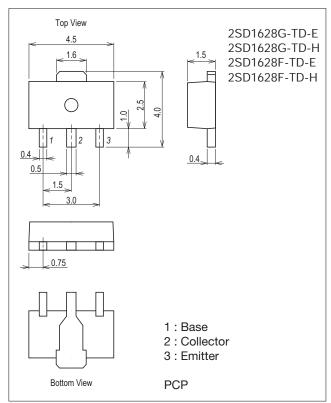
### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		60	V
Collector-to-Emitter Voltage	VCEO		20	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		6	V
Collector Current	IC		5	Α
Collector Current (Pulse)	ICP		8	А

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#### **Package Dimensions**

unit : mm (typ) 7007B-004



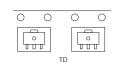
#### **Product & Package Information**

• Package : PCP

• JEITA, JEDEC : SC-62, SOT-89, TO-243

• Minimum Packing Quantity: 1,000 pcs./reel

#### Packing Type: TD Marking





#### **Electrical Connection**



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#### Continued from preceding page.

Parameter Symbol		Conditions	Ratings	Unit
Collector Dissipation	Pc		500	mW
Collector dissipation	PC	When mounted on ceramic substrate (250mm <sup>2</sup> x0.8mm)	1.5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

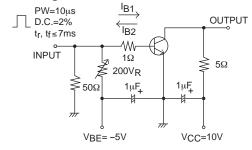
#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Symbol		min	typ	max	UIIIL	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =50V, I <sub>E</sub> =0A			100	nA	
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0A			100	nA	
DC Current Gain	hFE1	V <sub>CE</sub> =2V, I <sub>C</sub> =0.5A	120*		560*		
DC Current Gain	h <sub>FE</sub> 2	V <sub>CE</sub> =2V, I <sub>C</sub> =3A	95				
Gain-Bandwidth Product	n-Bandwidth Product fT VCE=10V, IC=50mA			120		MHz	
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		45		pF	
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	IC=3A, IB=60mA			500	mV	
Base-to-Emitter Saturation Voltage VBE(sat)		IC=3A, IB=60mA			1.5	V	
Turn-ON Time	ton			30		ns	
Storage Time	t <sub>stg</sub>	See specified Test Circuit.		300		ns	
Fall Time	t <sub>f</sub>			40		ns	

### $^{\star}$ : The 2SD1628 is classified by 0.5A $h_{\mbox{\scriptsize FE}}$ as follows :

Rank	Е	F	G	
hFE	120 to 200	160 to 320	280 to 560	

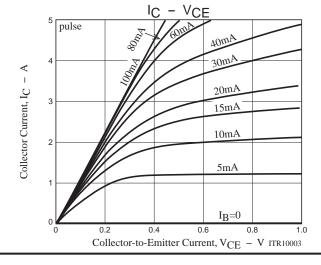
#### **Switching Time Test Circuit**

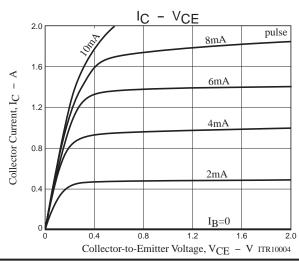


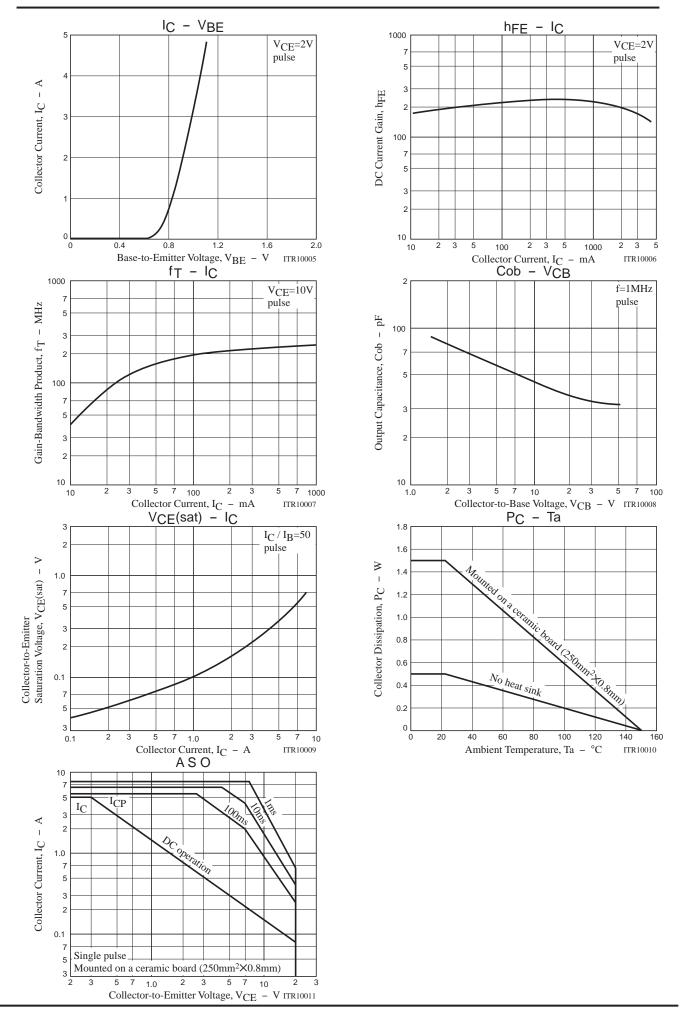
 $I_{C}=10I_{B1}=-10I_{B2}=2A$ 

### **Ordering Information**

Device Package		Chinning	m.o.m.o.	
Device	Package	Shipping	memo	
2SD1628G-TD-E	PCP	1,000pcs./reel	Pb Free	
2SD1628G-TD-H	PCP	1,000pcs./reel	Pb Free and Halogen Free	
2SD1628F-TD-E	PCP	1,000pcs./reel	Pb Free	
2SD1628F-TD-H	PCP	1,000pcs./reel	Pb Free and Halogen Free	





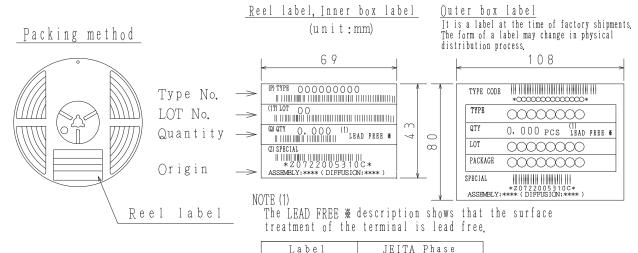


#### **Bag Packing Specification**

#### 2SD1628G-TD-E, 2SD1628G-TD-H, 2SD1628F-TD-E, 2SD1628F-TD-H

#### 1. Packing Format

Pa	ckage Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format		
		Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)		
	PCP	PCP	1, 000	4,000	24,000	4 reels contained	6 inner boxes contained		
						Dimensions:mm (external)	Dimensions:mm (external)		
						183×72×185	440×195×210		



LEAD FREE 3

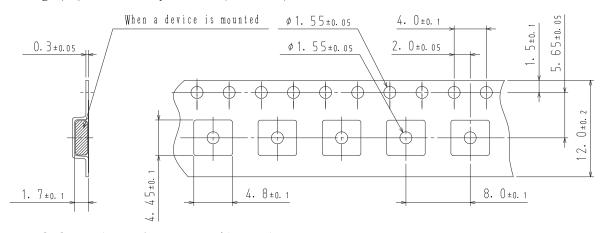
LEAD FREE 4

JEITA Phase 3A

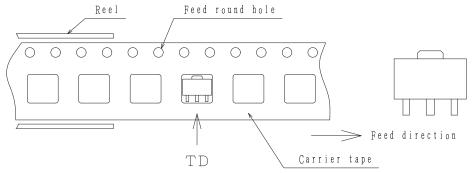
JEITA Phase 3

#### 2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

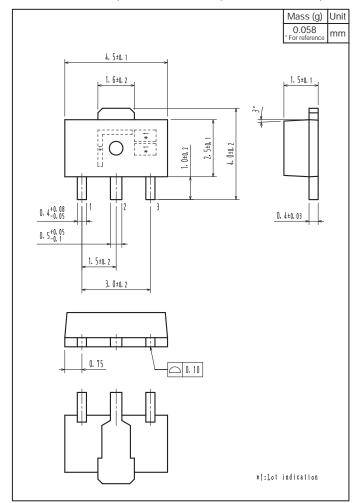


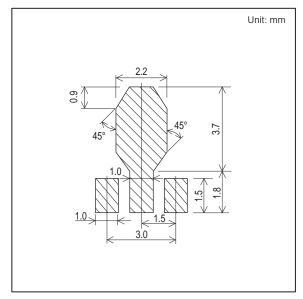
Those with pin 1 index on the feed hole side·····TD

#### **Outline Drawing**

#### **Land Pattern Example**

 $2SD1628G-TD-E,\, 2SD1628G-TD-H,\, 2SD1628F-TD-E,\, 2SD1628F-TD-H$ 





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